

High power NPN transistor

Features

- High power dissipation
- Low collector-emitter saturation voltage

Description

The device is a planar NPN transistor mounted in TO-3 metal case. It is intended for linear amplifiers and inductive switching applications.

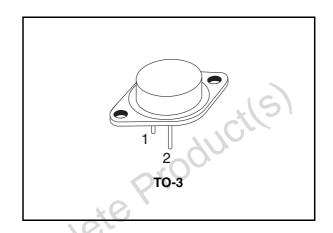


Figure 1. Internal schematic diagram

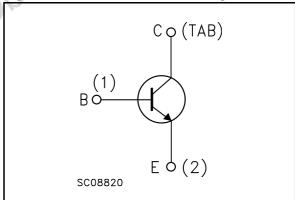


Table 1. Device summary

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Order code	Marking	Package	Packaging
2N3773	2N3773	TO-3	Tray

Electrical ratings 2N3773

1 Electrical ratings

Table 2. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V_{CEO}	Collector-emitter voltage (I _B = 0)	140	٧
V _{CEV}	Collector-emitter voltage (V _{BE} = -1.5 V)	160	٧
V _{CBO}	Collector-base voltage (I _E = 0)	160	V
V _{EBO}	Emitter-base voltage (I _C = 0)	7	V
I _C	Collector current	16	S A
I _{CM}	Collector peak current (t _P < 5 ms)	30	Α
Ι _Β	Base current	4	Α
I _{BM}	Base peak current (t _P < 1 ms)	15	Α
P _{tot}	Total dissipation at T _c ≤ 25 °C	150	W
T _{stg}	Storage temperature	-65 to 200	°C
Tj	Max. operating junction temperature	200	°C

Table 3. Thermal data

	Symbol Parameter			Value	Unit
	R _{thj-case}	Thermal resistance junction-case Max		1.17	°C/W
:-50/6	ie P	¹ OQIO			
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Electrical characteristics 2

 $(T_{case} = 25 \, ^{\circ}C \text{ unless otherwise specified})$

Table 4. **Electrical characteristics**

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
I _{CEV}	Collector cut-off current (V _{BE} = -1.5 V)	V _{CE} = 140 V V _{CE} = 140 V T _C = 150 °C			2 10	mA mA
I _{CEO}	Collector cut-off current (I _B = 0)	V _{CE} = 120 V			10	mA
I _{CBO}	Collector cut-off current (I _E = 0)	V _{CB} = 140 V			2	mA
I _{EBO}	Emitter cut-off current (I _C = 0)	V _{EB} = 7 V	, (0	0.	5	mA
V _{CEO(sus)} (1)	Collector-emitter sustaining voltage (I _B = 0)	I _C = 0.2 A	140			V
V _{CEV(sus)} (1)	Collector-emitter sustaining voltage (V _{BE} = -1.5 V)	I _C = 0.1 A	160			V
V _{CER(sus)} (1)	Collector-emitter sustaining voltage (R _{BE} = 100 Ω)	I _C = 0.2 A	150			V
V _{CE(sat)} (1)	Collector-emitter saturation voltage	$I_C = 8 \text{ A}$ $I_B = 0.8 \text{ A}$ $I_C = 16 \text{ A}$ $I_B = 3.2 \text{ A}$			1.4 4	V V
V _{BE} (1)	Base-emitter voltage	I _C = 8 A V _{CE} = 4 V			2.2	V
h _{FE} (1)	DC current gain	I _C = 8 A	15 5		60	
I _{s/b}	Second Breakdown Collector Current	V _{CE} = 30 V t = 1 s (non repetitive)	5			Α
	Collector Current		3			

^{1.} Pulsed: Pulse duration = 300 μ s, duty cycle \leq 2 %

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3 Package mechanical data

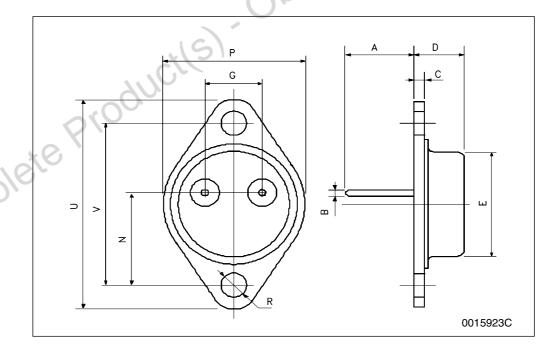
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Obsolete Product(s). Obsolete Product(s)

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TO-3 mechanical data

DIM.	mm.				
DIIVI.	min.	typ	max.		
А	11.00		13.10		
В	0.97		1.15		
С	1.50		1.65		
D	8.32		8.92		
E	19.00		20.00		
G	10.70		11.10		
N	16.50		17.20		
Р	25.00	1	26.00		
R	4.00	3/2	4.09		
U	38.50	7/6,	39.30		
V	30.00	1250.	30.30		



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Revision history 2N3773

4 Revision history

Table 5. Document revision history

Date	Revision	Changes	
03-Apr-2006	1	Initial release.	
10-Oct-2008	2	Content reworked to improve readability, no technical changes.	

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